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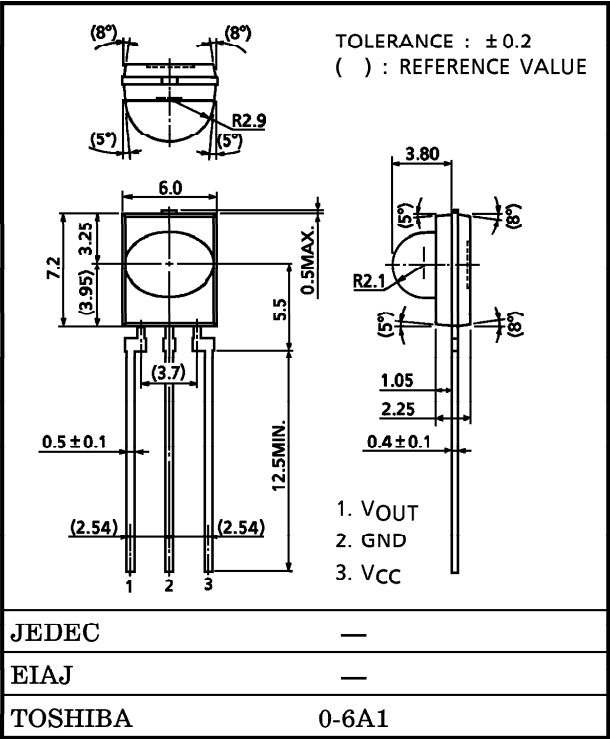
TOSHIBA PHOTO IC Si MONOLYTHIC PHOTO IC

TPS831

HIGH-SPEED OPTICAL REMOTE CONTROLLERS
CORDLESS CONTROLLERS FOR VIDEO-GAMES
ELECTRONIC ORGANIZERS AND OTHER NEW
PORTABLE INFORMATION TOOLS
IR DATA COMMUNICATION

- The TPS831 is a photo IC which includes a photodiode, I-V converter, band-pass filter and AGC amplifier on a single chip.
- The device's carrier frequency is as follows
: $f_0=455\text{kHz}$
- The device's supply voltage is as follows
: $V_{CC}=5\text{V}$
- Visible light cut-off frequency : 800nm
- The TLN105B and TLN115A are available as infrared LEDs for remote controllers.

Unit : mm



Weight : 0.3g (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	VCC	7	V
Operating Temperature Range	Topr	-20~60	°C
Storage Temperature Range	Tstg	-30~100	°C
Soldering Temperature Range (5s)	Tsol	260	°C

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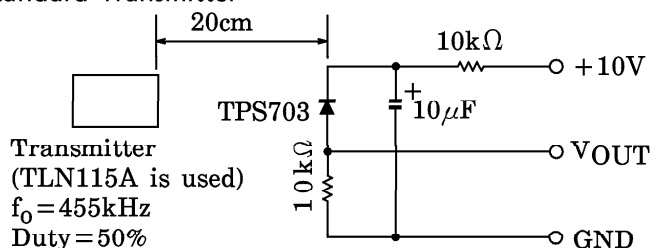
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OPTO-ELECTRICAL CHARACTERISTICS ($V_{CC} = 5V$, $T_a = 25^\circ C$, $C = 1000pF$: Note 1)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{CC}	—	3	5	7	V
Supply Current	I_{CC}	$E = 0$	—	1.2	3.0	mA
Electromagnetic Sensitivity	E_S	(Note 5)	—	250	—	V_{p-p}/m
Transmission Range	L (Note 3)	The burst wave shown in (Note 4) is transmitted by a standard transmitter. (Note 2)	3	5	—	m
High-Level Output Voltage	V_{OH}	External light intensity $< 500lx$ Output Current $< 10\mu A$	4.0	—	—	V
Low-Level Output Voltage	V_{OL}		—	—	0.5	V
ON Pulse Width	T_{ON}	External light intensity $< 500lx$ Output Current $< 10\mu A$	16	25	40	μs
OFF Pulse Width	T_{OFF}		—	63	—	μs
Carrier Frequency	f_0	—	—	455	—	kHz
Radiation Angle	θ_H	Horizontal angle, $L/2$ (Note 6)	± 55	± 63	—	$^\circ$
	θ_V	Vertical angle, $L/2$ (Note 6)	± 25	± 30	—	$^\circ$

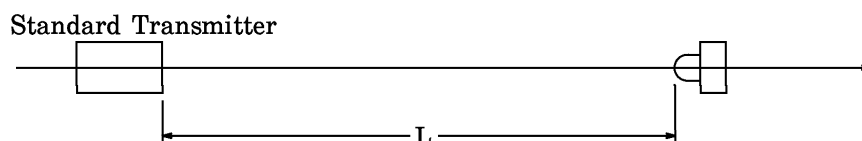
(Note 1) Measurements for the TPS831 are based on a standard circuit that includes a 1000pF capacitor between V_O and GND to prevent oscillation.

(Note 2) Standard Transmitter

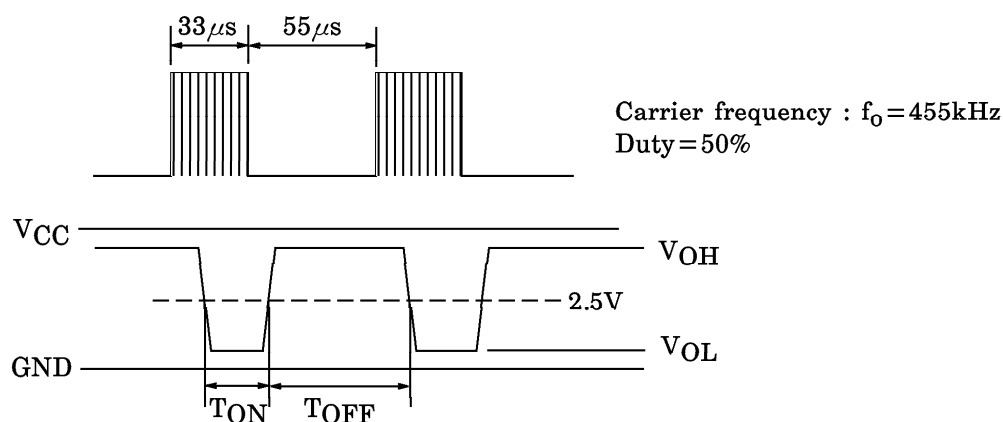


In the figure above, the transmitter shall be set as the output V_{OUT} will be 80mVpp. The TPS703 in this application has a short circuit current $I_{sc} = 1.24\mu A$ measured at $E = 0.1mW/cm^2$. (E is the radiant incidence using a CIE standard light source A)

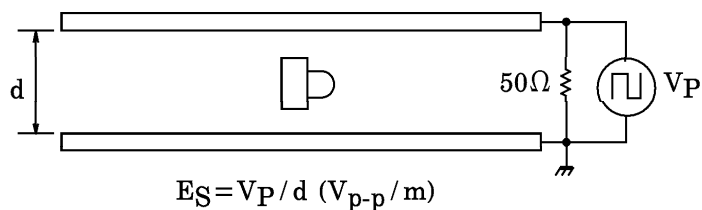
(Note 3) Transmission Distance L



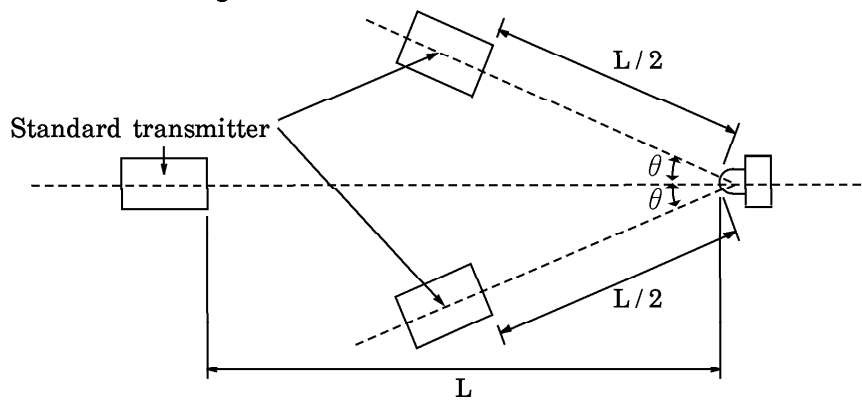
(Note 4) Burst Wave



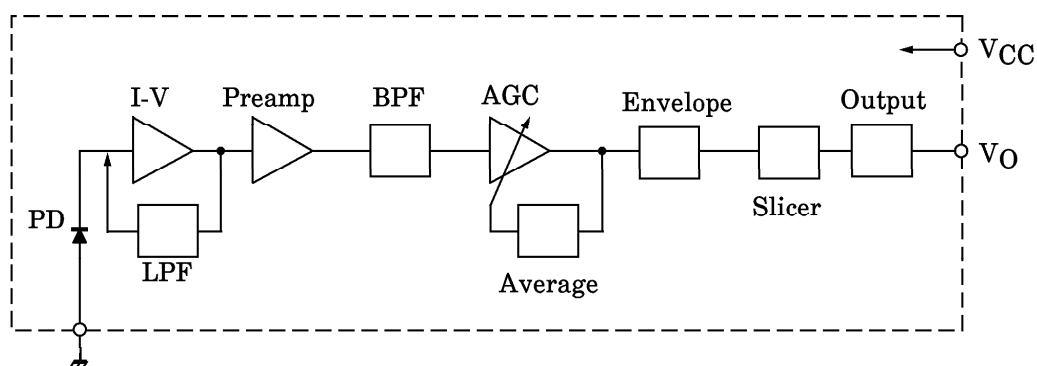
(Note 5) Electromagnetic Sensitivity



(Note 6) Radiation Angle



Circuit Block Diagram



PRECAUTIONS

1. If a lead is formed, it should be formed at a distance of 2mm from the body of the device. Forming the lead should not cause stress to the body of the device. Soldering must be performed after lead forming.
2. Insert a bypass condenser of up to $0.01\mu\text{F}$ between V_{CC} and GND near the device to stabilize the power supply line.
3. Within $100\mu\text{s}$ of V_{CC} turning on, the output voltage changes to stabilize the inner circuit.

